

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Currently Amended) A display device in which a thin film transistor is disposed on an insulative substrate, said thin film transistor comprising:
  - a first gate electrode; a gate insulating film; a semiconductor film which is formed on said gate insulating film and which has a channel;
  - a insulating film;
  - a reflective display electrode connected to a source which is formed in said semiconductor film, said display electrode being elongated so as to extend above said channel of said thin film transistor, andwherein a second gate electrode formed between said first gate electrode and said display electrode.
  
2. (Currently Amended) A display device in which a thin film transistor is disposed on an insulative substrate, said thin film transistor comprising:
  - a first gate electrode; a gate insulating film; a semiconductor film which is formed on said gate insulating film and which has a channel;
  - a insulating film;
  - a reflective display electrode connected to a source which is formed in said semiconductor film, said display electrode being elongated so as to extend above said channel of said thin film transistor; anda second gate electrode formed between said first gate electrode and said display electrode,

wherein said second gate electrode is connected with said first gate electrode.

3. (Original) A display device according to claim 2, wherein said second gate electrode is formed so as to be faced with said first gate electrode through said insulating film.

4. (Original) A display device according to claim 3, wherein said display electrode is rectangular.

5. (Original) A display device according to claim 1, wherein said channel is covered with a stopper insulating film.

6. (Original) A display device according to claim 5, wherein said stopper insulating film is made of an SiO<sub>2</sub> film.

7. (Original) A display device according to claim 5, wherein said stopper insulating film is made of a two-layered film of SiN and organic film.

8. (Original) A display device according to claim 1, wherein said first gate electrode is a double gate structured electrode divided above the channel.

9. (Original) A display device according to claim 8, wherein said second gate electrode is a double gate structured electrode divided corresponding to said first gate electrode.

10. (Canceled)

11. (Currently Amended) A display device according to claim [[10]] 1, wherein said reflective display electrode is made of Al-Nd alloy.

12. (Original) A display device according to claim 1, wherein said display electrode is an electrode used in a liquid display device.

13. (Original) A display device according to claim 1, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

14. (Previously Presented) A display device according to claim 1, wherein said thin film transistor further comprises:

a holding capacitance electrode;

wherein a capacitance electrode connected to the source region and the holding capacitance electrode are arranged relative to each other to constitute a capacitance; and

wherein the holding capacitance electrode is made of a same material ~~of~~ as the first gate electrode.

15. (Currently Amended) A display device according to claim 2, wherein a light ~~emitting~~ emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

16. (Previously Presented) A display device according to claim 2, wherein said thin film transistor further comprises:

a holding capacitance electrode;

wherein a capacitance electrode connected to the source region and the holding capacitance electrode are arranged relative to each other to constitute a capacitance; and

wherein the holding capacitance electrode is made of a same material as the first gate electrode.

17. (Currently Amended) A display device comprising:

an insulative substrate;  
a thin film transistor including a gate electrode, a gate insulating film and a channel region;  
a reflective display electrode connected to one of a source region of the thin film transistor and a drain region of the thin film transistor, said display electrode being extended above the channel region of the thin film transistor;  
an electrode provided between the channel region of the thin film transistor and the display electrode,  
wherein the electrode is connected to the gate electrode.

18. (Canceled)

19. (Original) A display device according to claim 17, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

20. (Previously Presented) A display device according to claim 17, further comprising:

a holding capacitance electrode;  
wherein a capacitance electrode connected to the source region and the holding capacitance electrode are arranged relative to each other to constitute a capacitance; and  
wherein the holding capacitance electrode is made of a same material as the first gate electrode.

21. (Currently Amended) A display device comprising:  
an insulative substrate;  
a thin film transistor including a gate electrode, a gate insulating film and a channel region;

a reflective display electrode connected to one of a source region of the thin film transistor and a drain region of the thin film transistor, said display electrode being extended above the channel region of the thin film transistor;

an electrode provided between the channel region of the thin film transistor and the display electrode,

wherein a gate voltage is applied to the electrode.

22. (Canceled)

23. (Currently Amended) A display device according to claim [[22]] 21, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

24. (Currently Amended) A display device according to claim [[22]] 21, further comprising:

a holding capacitance electrode line;

wherein a capacitance electrode connected to the source region and the holding electrode line are arranged relative to each other to constitute a capacitance; and

wherein the holding capacitance electrode is made of a same material as the first gate electrode.

25. (New) The display device according to claim 1 wherein the second gate electrode is larger than the first gate electrode.

26. (New) The display device according to claim 2 wherein the second gate electrode is larger than the first gate electrode.

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27. (New) The display device according to claim 17 wherein the second gate electrode is larger than the first gate electrode.